

Fuji Discrete Package IGBT

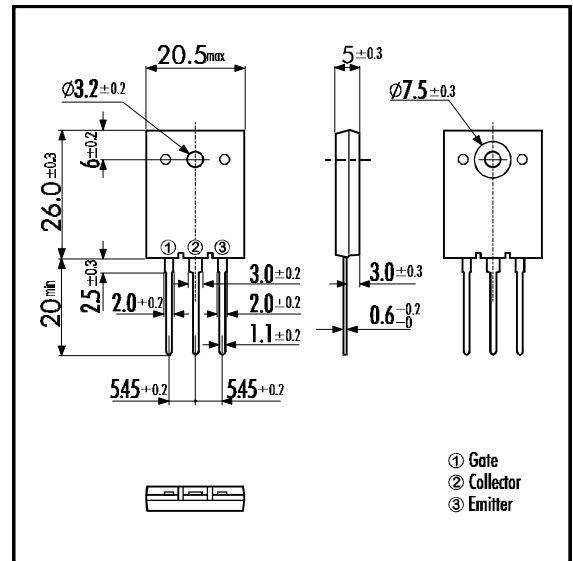
■ Outline Drawing

■ Features

- Square RBSOA
- Low Saturation Voltage
- Less Total Power Dissipation
- Minimized Internal Stray Inductance

■ Applications

- High Power Switching
- A.C. Motor Controls
- D.C. Motor Controls
- Uninterruptible Power Supply

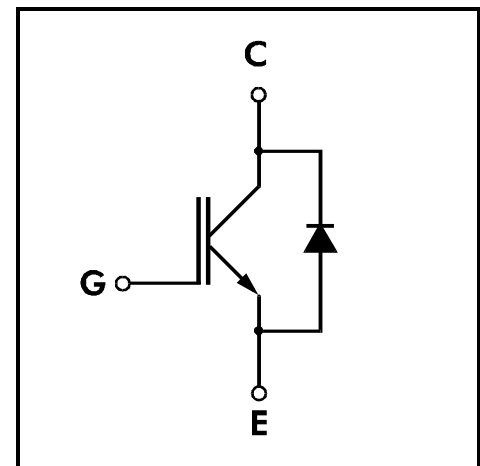


■ Maximum Ratings and Characteristics

• Absolute Maximum Ratings (T_c=25°C)

Items	Symbols	Ratings	Units
Collector-Emitter Voltage	V _{CES}	600	V
Gate -Emitter Voltage	V _{GES}	± 20	V
Collector Current	DC T _c = 25°C	I _{C 25}	58
	DC T _c =100°C	I _{C 100}	30
	1ms T _c = 25°C	I _{C PULSE}	232
IGBT Max. Power Dissipation	P _C	220	W
FWD Max. Power Dissipation	P _C	120	W
Operating Temperature	T _j	+150	°C
Storage Temperature	T _{stg}	-40 ~ +150	°C
Mounting Screw Torque		70	Nm

■ Equivalent Circuit



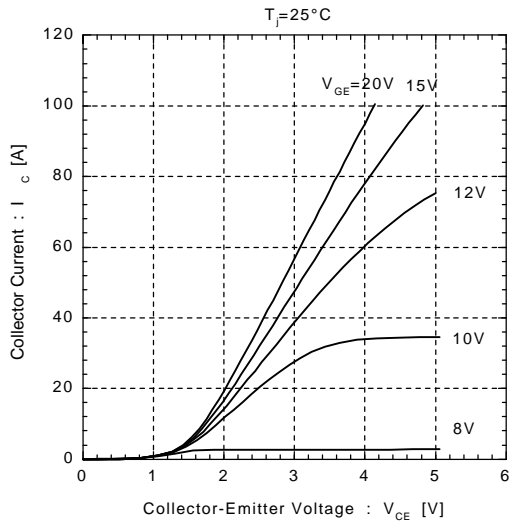
• Electrical Characteristics (at T_j=25°C)

Items	Symbols	Test Conditions	Min.	Typ.	Max.	Units	
Zero Gate Voltage Collector Current	I _{CES}	V _{GE} =0V V _{CE} =600V			1.0	mA	
Gate-Emitter Leakage Current	I _{GES}	V _{CE} =0V V _{GE} =± 20V			20	μA	
Gate-Emitter Threshold Voltage	V _{GE(th)}	V _{GE} =20V I _C =30mA	5.5		8.5	V	
Collector-Emitter Saturation Voltage	V _{CE(sat)}	V _{GE} =15V I _C =30A			3.0	V	
Input capacitance	C _{ies}	V _{GE} =0V		1900		pF	
Output capacitance	C _{oes}	V _{CE} =10V		400			
Reverse Transfer capacitance	C _{res}	f=1MHz		100			
Switching Time	Turn-on Time	t _{ON}	V _{CC} =300V			1.2	μs
		t _r	I _C =30A			0.6	
	Turn-off Time	t _{OFF}	V _{GE} =±15V			1.0	
		t _f	R _G =82Ω			0.35	
	Turn-on Time	t _{ON}	V _{CC} =300V		0.16		μs
		t _r	I _C =30A		0.11		
		t _{OFF}	V _{GE} =+15V		0.30		
		t _f	R _G =8Ω			0.35	
Diode Forward On-Voltage	V _F	I _F =30A V _{GE} =0V			3.0	V	
Reverse Recovery Time	t _{rr}	I _F =30A, V _{GE} =-10V, di/dt=100A/μs			300	ns	

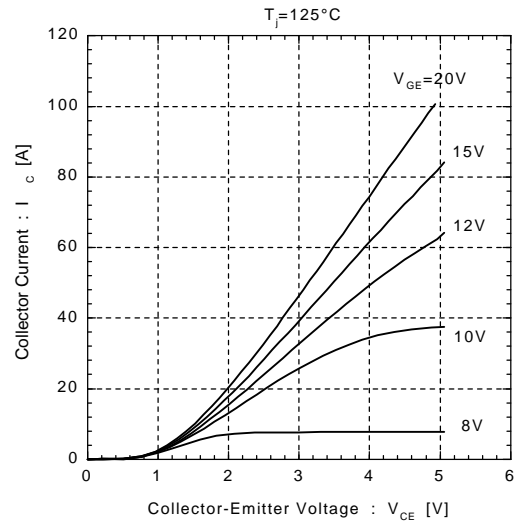
• Thermal Characteristics

Items	Symbols	Test Conditions	Min.	Typ.	Max.	Units
Thermal Resistance	R _{th(i-c)}	IGBT			0.56	°C/W
	R _{th(i-e)}	Diode			1.04	

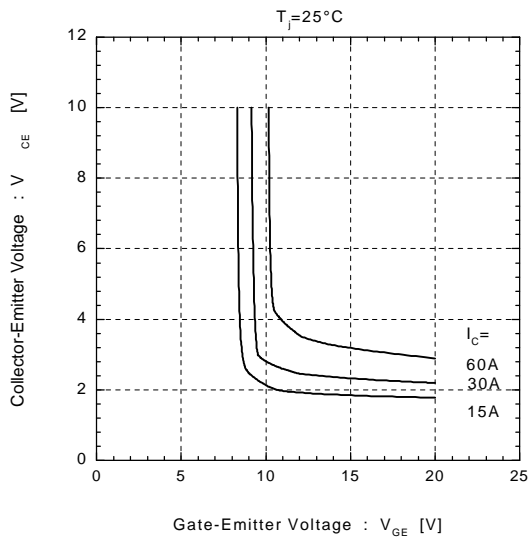
Collector Current vs. Collector-Emittor Voltage



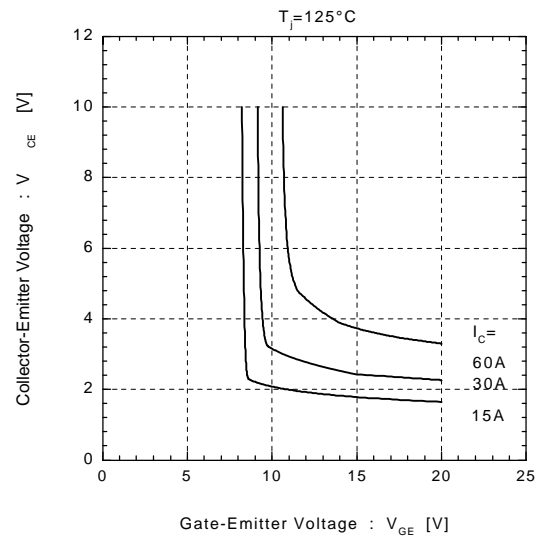
Collector Current vs. Collector-Emittor Voltage



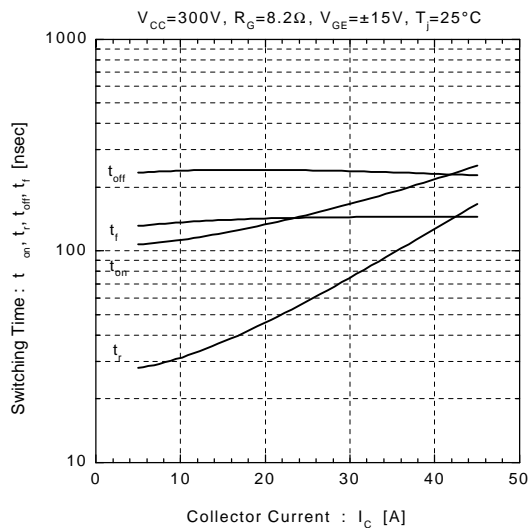
Collector-Emittor Voltage vs. Gate-Emittor Voltage



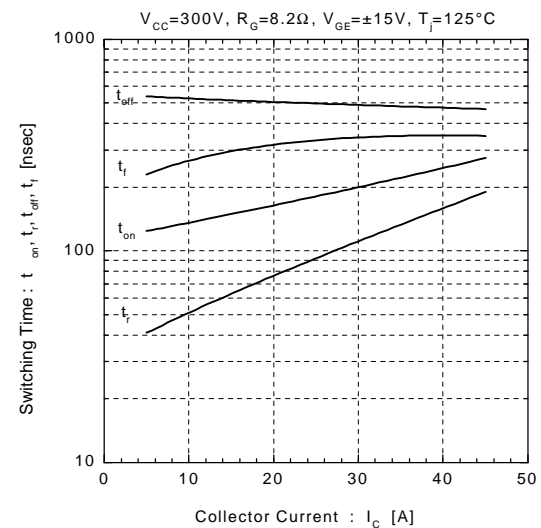
Collector-Emittor Voltage vs. Gate-Emittor Voltage

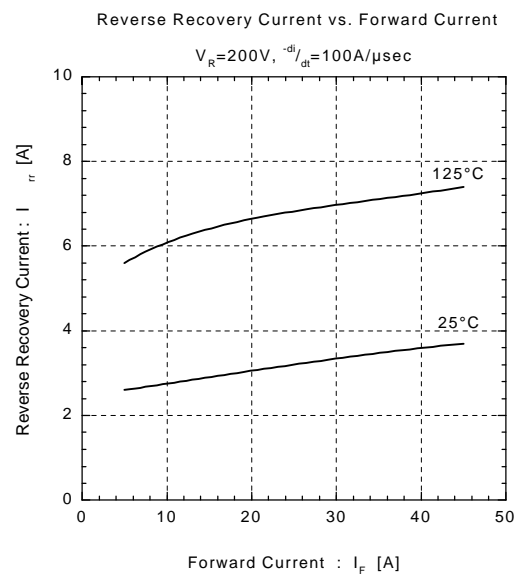
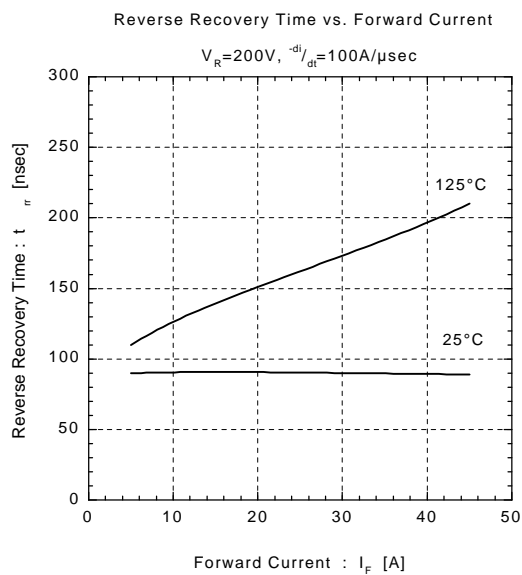
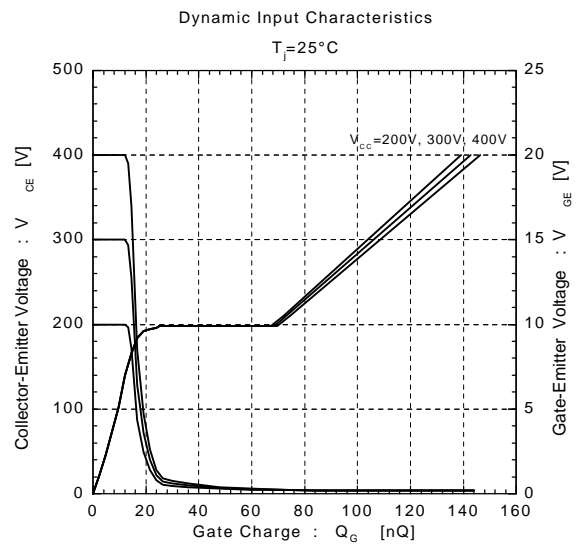
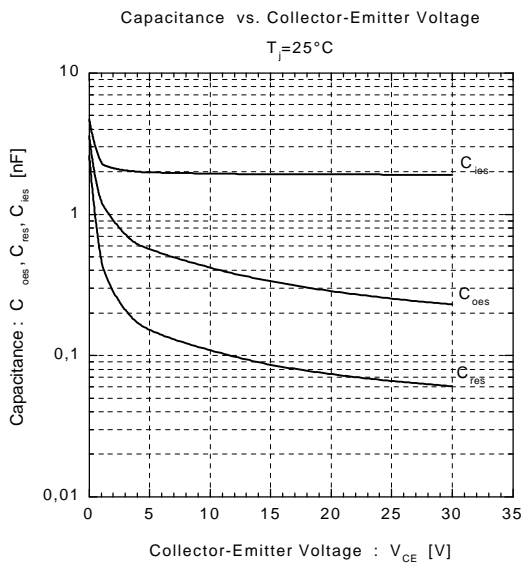
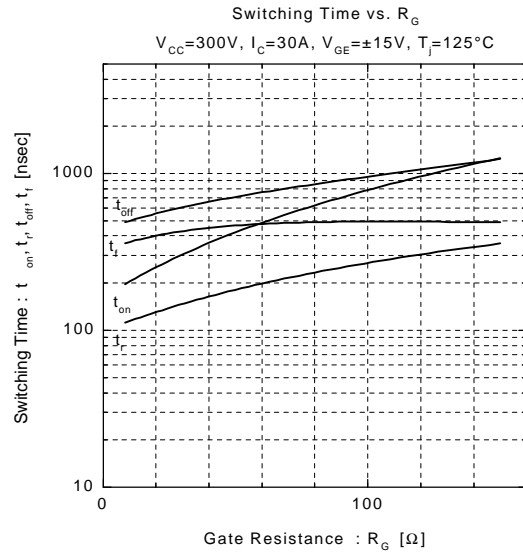
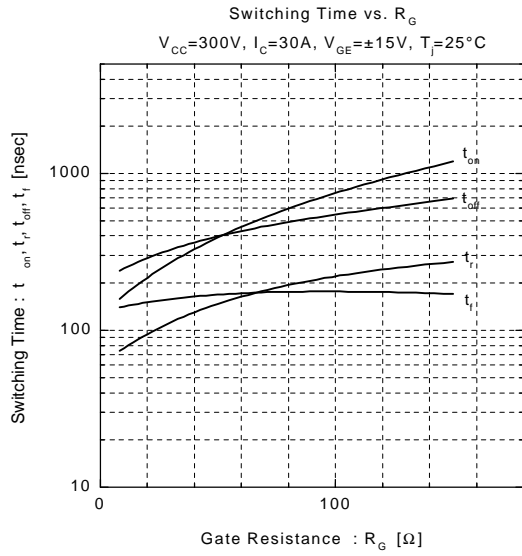


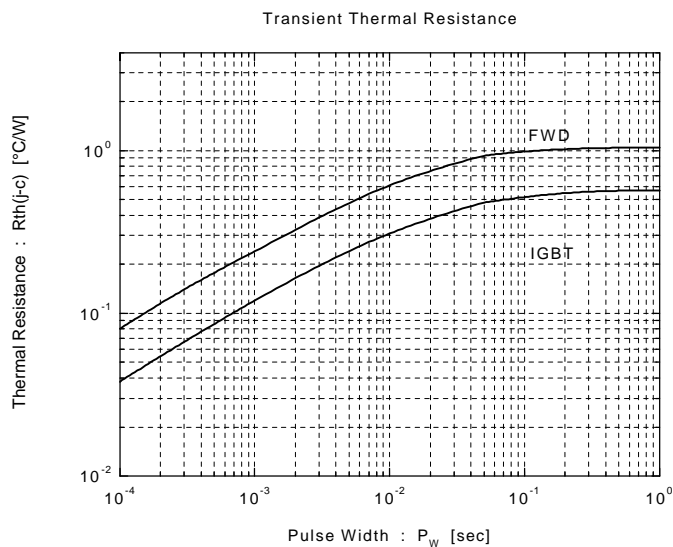
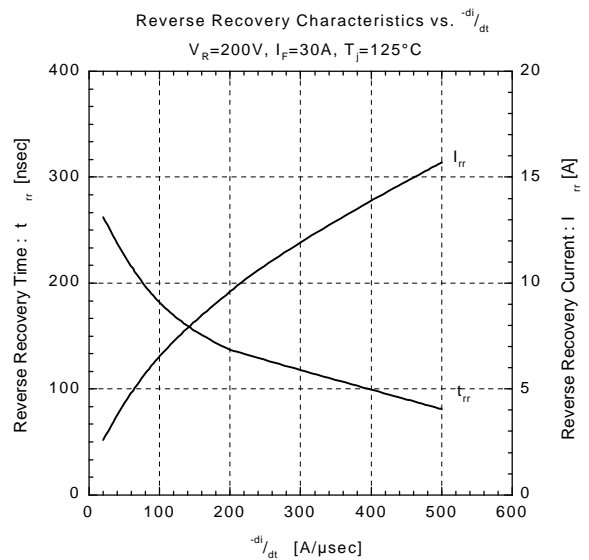
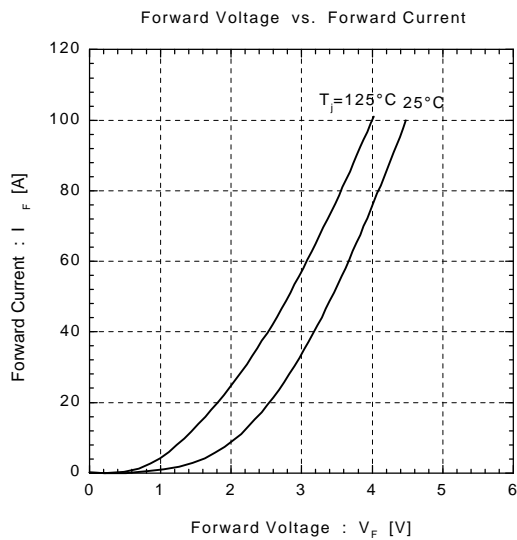
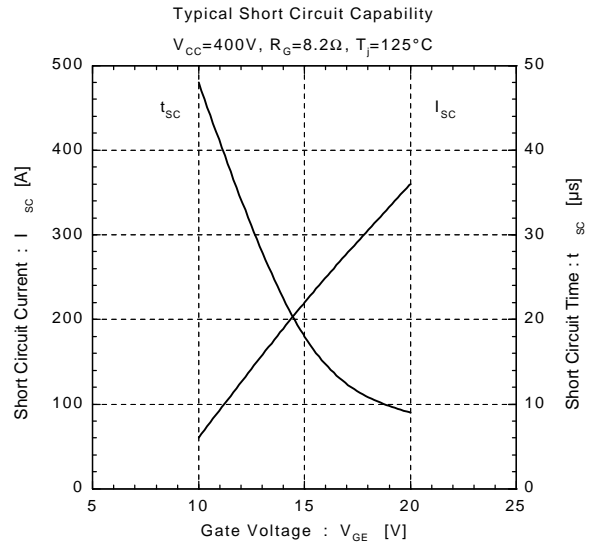
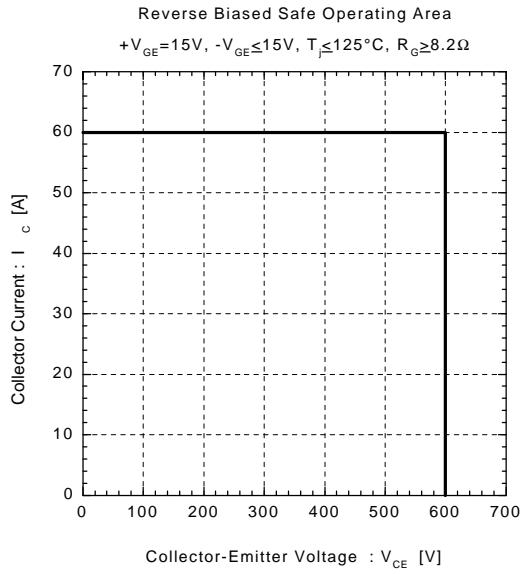
Switching Time vs. Collector Current



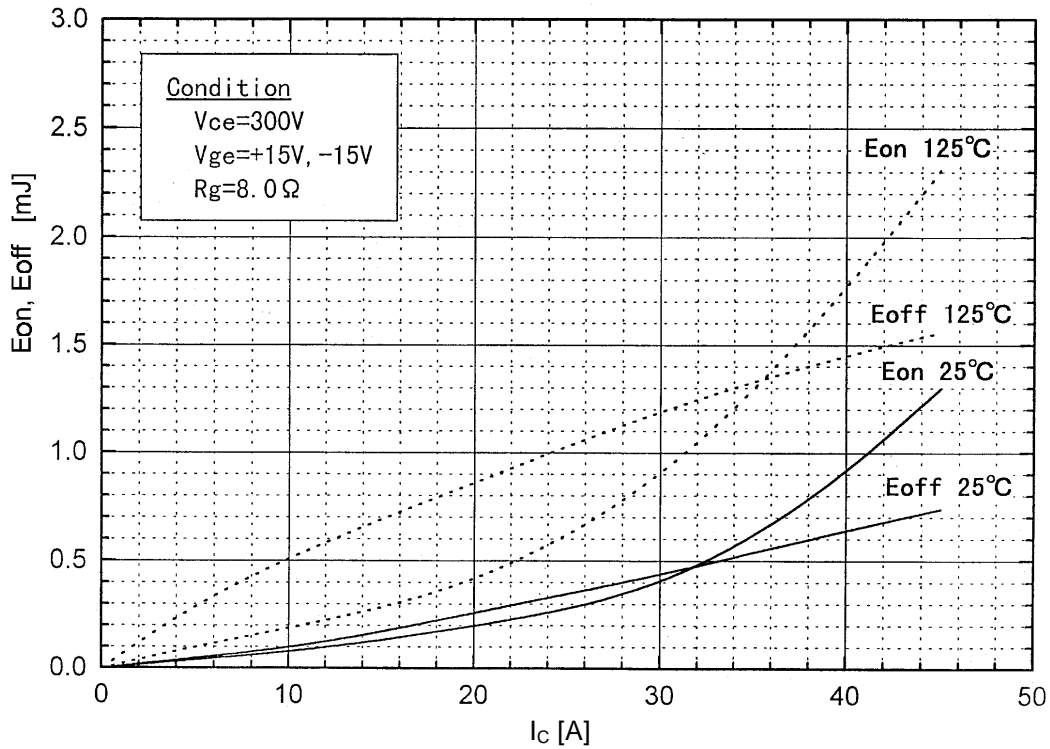
Switching Time vs. Collector Current



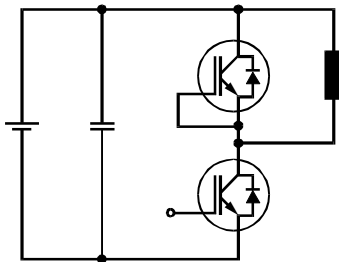




Switching losses (E_{on} , E_{off} vs. I_c)



Test Circuit



Switching waveforms

